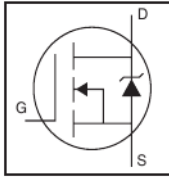


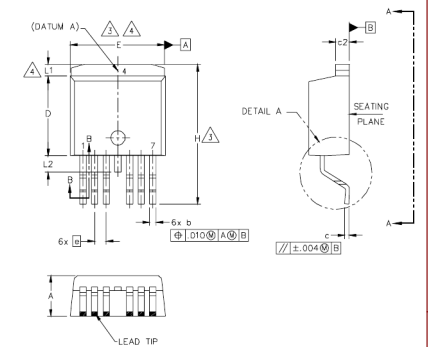
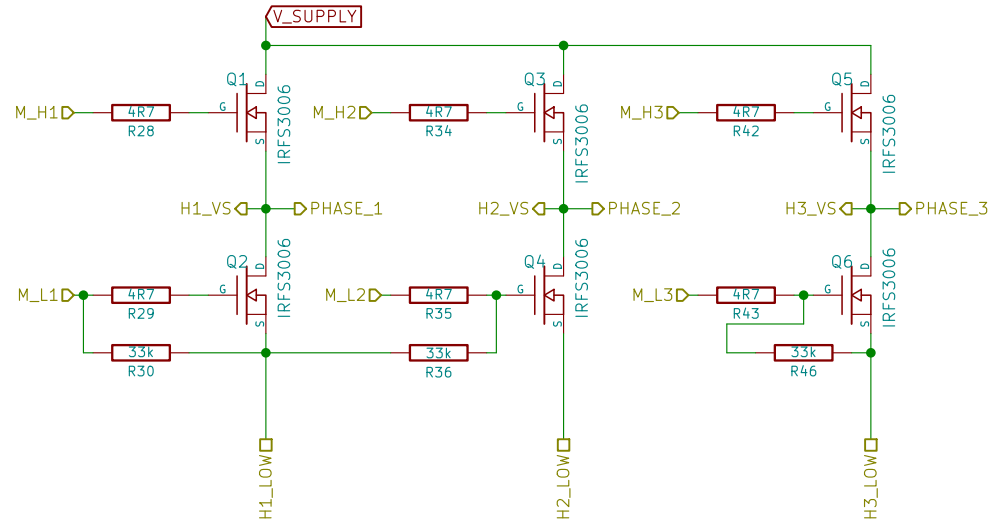
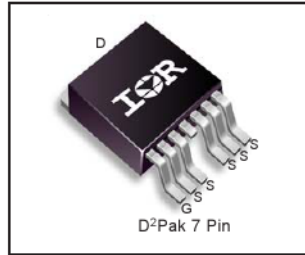
[illegible]

Rev: 4.5
Id: 1/7

HEXFET® Power MOSFET



V_{DS}	60V
$R_{DS(on)}$ typ.	1.5m Ω
max.	2.1m Ω
I_D (Silicon Limited)	293A①
I_D (Package Limited)	240A



Absolute Maximum Ratings

Symbol	Parameter	Max.	Units
I_D @ $T_C = 25^\circ\text{C}$	Continuous Drain Current, $V_{DS} = 10\text{V}$ (Silicon Limited)	293①	A
I_D @ $T_C = 100^\circ\text{C}$	Continuous Drain Current, $V_{DS} = 10\text{V}$ (Silicon Limited)	207 ②	
I_D @ $T_C = 25^\circ\text{C}$	Continuous Drain Current, $V_{DS} = 10\text{V}$ (Package Limited)	240	
I_{DS}	Pulsed Drain Current ③	1172	A
P_D @ $T_C = 25^\circ\text{C}$	Maximum Power Dissipation	375	W
	Linear Derating Factor	2.5	W/°C
V_{GS}	Gate-to-Source Voltage	± 20	V
dv/dt	Peak Diode Recovery ④	11	V/ns
T_J	Operating Junction and Storage Temperature Range	-55 to $+175$	°C
T_{SOL}	Soldering Temperature, for 10 seconds (1.6mm from case)	300	
	Mounting torque, 6-32 or M3 screw	10lb-in (1.1N-m)	

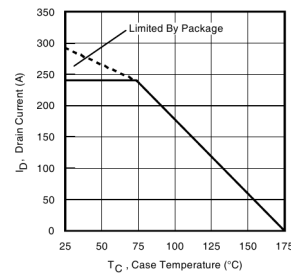


Fig 9. Maximum Drain Current vs. Case Temperature

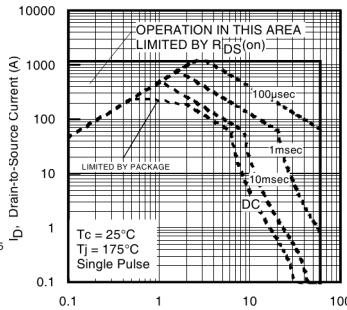


Fig 8. Maximum Safe Operating Area

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Sheet: /Power MOSFETS/

File: mosfets.sch

Title: BLDC Driver 4.5

Size: A4 Date: 25 Aug 2014

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Rev: 4.5

Id: 2/7

LM73 2.7V, SOT, 11-to-14 Bit Digital Temperature Sensor with 2-Wire Interface

FEATURES

- Single Address Pin Offers Choice of Three Selectable Addresses per Version for a Total of Six Possible Addresses.
- SMBus and I²C-Compatible Two-Wire Interface
- Supports 400 kHz Operation
- Shutdown Mode with One-Shot Feature Available for Very Low Average Power Consumption
- Programmable Digital Temperature Resolution from 11 Bits to 14 Bits.
- Fast Conversion Rate Ideal for Quick Power Up and Measuring Rapidly Changing Temperature
- Open-Drain ALERT Output Pin Goes Active When Temperature is Above a Programmed Temperature Limit
- Very Stable, Low-Noise Digital Output.
- UL Recognized Component

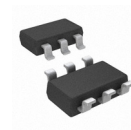
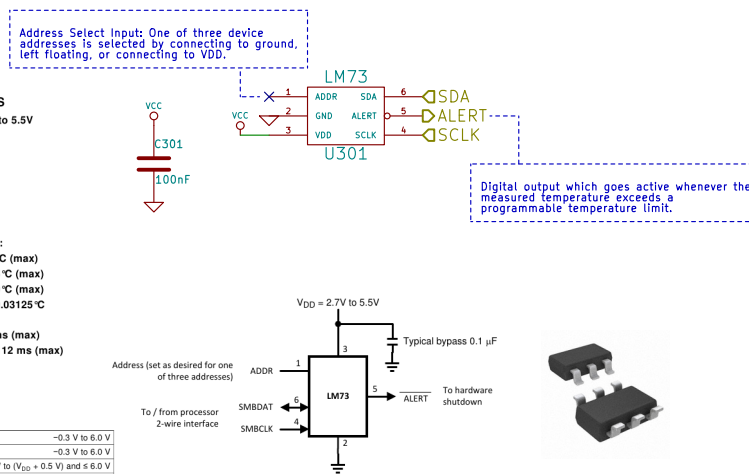
KEY SPECIFICATIONS

- Supply Voltage: 2.7V to 5.5V
- Supply Current:
 - Operating:
 - 320 μ A (typ)
 - 495 μ A (max)
 - Shutdown:
 - 8 μ A (max)
 - 1.9 μ A (typ)
- Temperature Accuracy:
 - -10°C to 80°C: $\pm 1.0^{\circ}$ C (max)
 - -25°C to 115°C: $\pm 1.5^{\circ}$ C (max)
 - -40°C to 150°C: $\pm 2.0^{\circ}$ C (max)
- Resolution: 0.25°C to 0.03125°C
- Conversion Time:
 - 11-bit (0.25°C): 14 ms (max)
 - 14-bit (0.03125°C): 112 ms (max)

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Supply Voltage	-0.3 V to 6.0 V
Voltage at SMBCLK and SMBDAT pins	-0.3 V to 6.0 V
Voltage at All Other Pins	-0.3 V to (V _{DD} + 0.5 V) and ≤ 6.0 V
Input Current at Any Pin ⁽²⁾	± 5 mA
Storage Temperature	-65°C to +150°C
ESD Susceptibility ⁽³⁾	Human Body Model Machine Model
	2000 V 200 V

Soldering process must comply with Texas Instruments' Reflow Temperature Profile specifications. Refer to www.ti.com/packaging.⁽⁴⁾



Mrk Industries

Sheet: /I²C temp sensor/

File: temp.sch

Title: I²C digital temperature sensor

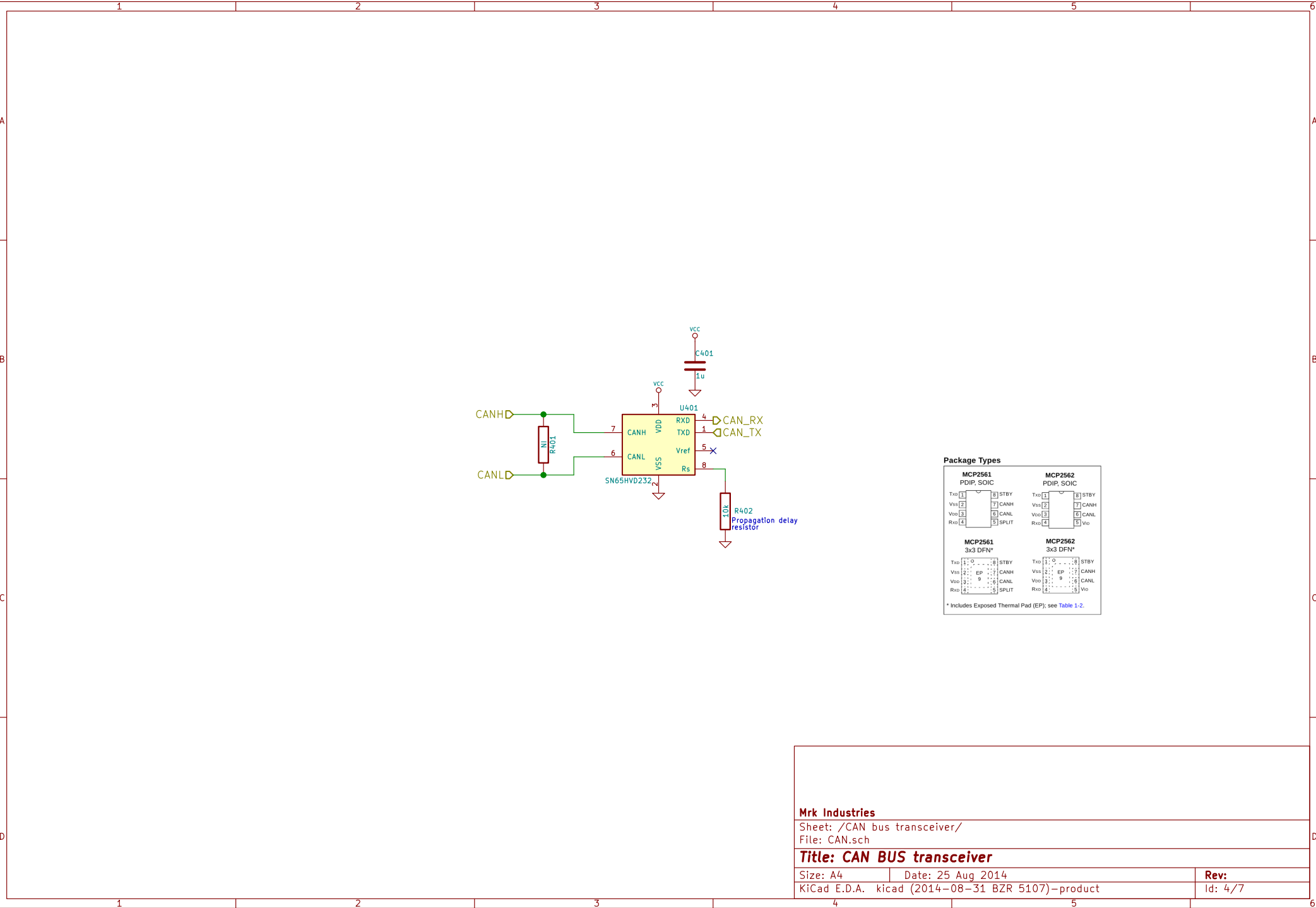
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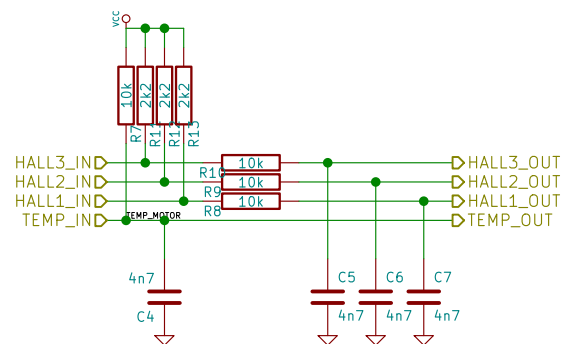
Date: 25 Aug 2014

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Id: 3/7





Sheet: /Filters/
File: hall_filters.sch

Title:

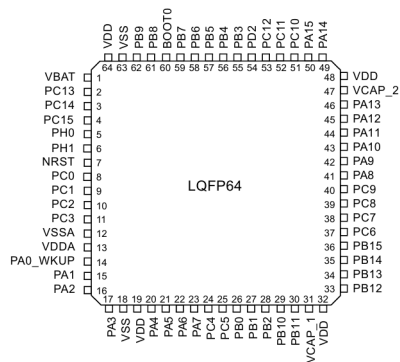
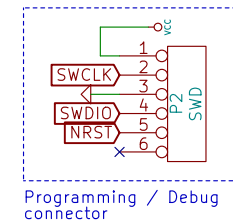
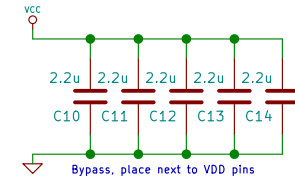
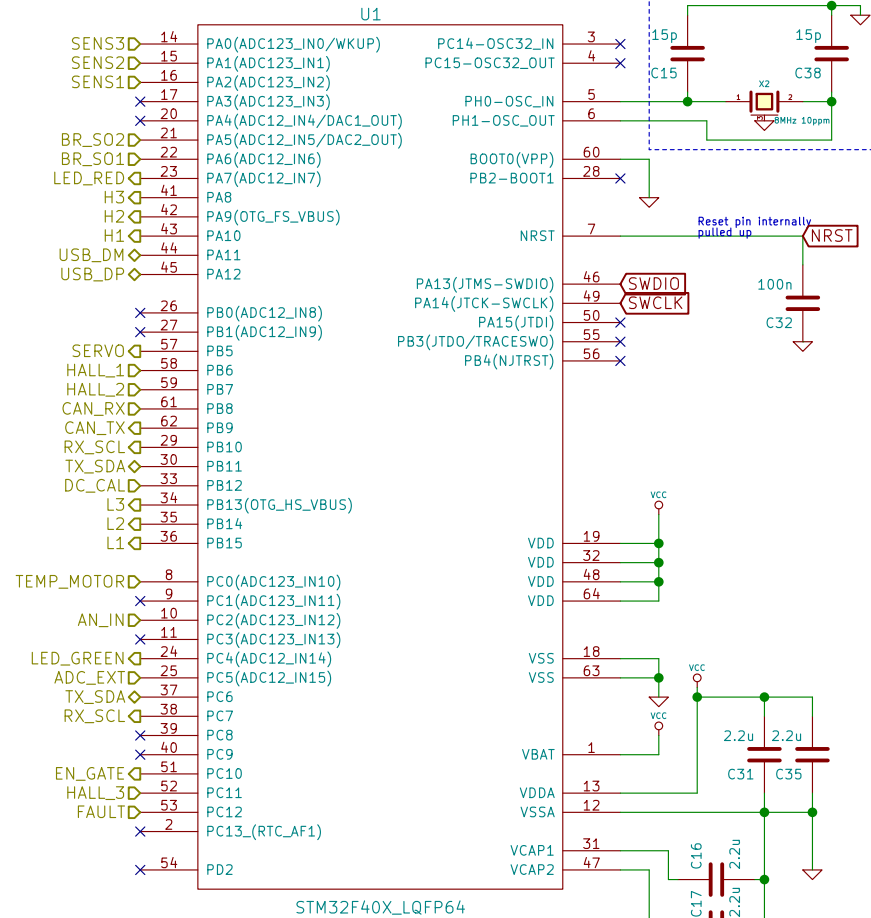
Size: A4 Date: 25 Aug 2014
KiCad E.D.A. kicad (2014-08-31 BZR 5107)-product

Rev:
Id: 5/7



STM32F405xx STM32F407xx

ARM Cortex-M4 32b MCU+FPU, 210DMIPS, up to 1MB Flash/192+4KB RAM, USB
OTG HS/FS, Ethernet, 17 TIMs, 3 ADCs, 15 comm. interfaces & camera



Benjamin Vedder

Sheet: /MCU/

File: STM32F4_64LQFP.sch

Title: BLDC Driver 4.5

Size: A4

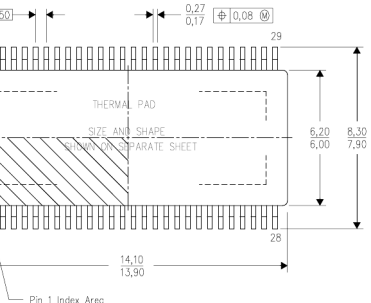
Date: 25 Aug 2014

KiCad E.D.A. kicad (2014-08-31 BZR 5107)-product

Rev: 4.5

Id: 6/7

- **Operating Supply Voltage 8V–60V**
- **2.3A Sink and 1.7A Source Gate Drive Current Capability**
- **Integrated Dual Shunt Current Amplifiers With Adjustable Gain and Offset**
- **Integrated Buck Converter to Support up to 1.5A External Load**
- **Independent Control of 3 or 6 PWM Inputs**
- **Bootstrap Gate Driver With 100% Duty Cycle Support**
- **Programmable Dead Time to Protect External FETs from Shoot Through**
- **Programmable Overcurrent Protection of External MOSFETs**
- **Thermally Enhanced 56-Pin TSSOP Pad Down DCA Package**



RECOMMENDED OPERATING CONDITIONS			MIN	TYP	MAX	UNITS
PVDD1	DC supply voltage PVDD1 for normal operation	Relative to PGND	8	60	V	
PVDD2	DC supply voltage PVDD2 for buck converter		3.5	60	V	
CAVDD	External capacitance on AVDD pin (ceramic cap) 20% tolerance			1	μ F	
CVDD	External capacitance on DVDD pin (ceramic cap) 20% tolerance			1	μ F	
CVDD2	External capacitance on GVDD pin (ceramic cap) 20% tolerance			2.2	μ F	
CP	Filter cap or charge pump caps (between CP1 and CP2) (ceramic cap) 20% tolerance			22	nF	
CBST	Bootstrap cap (ceramic cap)			100	nF	
I _{ON_EN}	Input current of digital pins when EN_GATE is high			100	μ A	
I _{ON_DIS}	Input current of digital pins when EN_GATE is low			1	μ A	
I _{CON}	Maximum capacitance on digital input pin			10	pF	
C _{O_PA}	Maximum output capacitance on outputs of shunt amplifier			20	pF	
R _{INTC}	Dead time control resistor range. Time range is 50ns (\leq NDT) to 1500ns (\geq 150ns) with a linear approximation		0	150	k Ω	
V _{AULT}	FAULT pin sink current, Open-drain	V = 0.4 V			mA	
I _{OC_{FW}}	OC _{FW} pin sink current, Open-drain	V = 0.4 V			mA	
V _{REF}	External voltage reference voltage for current shunt amplifiers		2	6	V	
f _{SW}	Operating switching frequency of gate driver	Gq(TOT) = 25 nC or total 30 mA gate driver average current			kHz	
T _A	Ambient temperature		-40	125	°C	

Rev: 4.5
Id: 7/7